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The following document contains information on Cypress products. The document has the series name, product name, and ordering part numbering with the prefix “MB”. However, Cypress will offer these products to new and existing customers with the series name, product name, and ordering part number with the prefix “CY”.

#### **How to Check the Ordering Part Number**

1. Go to [www.cypress.com/pcn](http://www.cypress.com/pcn).
2. Enter the keyword (for example, ordering part number) in the **SEARCH PCNS** field and click **Apply**.
3. Click the corresponding title from the search results.
4. Download the Affected Parts List file, which has details of all changes

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#### **About Cypress**

Cypress is the leader in advanced embedded system solutions for the world's most innovative automotive, industrial, smart home appliances, consumer electronics and medical products. Cypress' microcontrollers, analog ICs, wireless and USB-based connectivity solutions and reliable, high-performance memories help engineers design differentiated products and get them to market first. Cypress is committed to providing customers with the best support and development resources on the planet enabling them to disrupt markets by creating new product categories in record time. To learn more, go to [www.cypress.com](http://www.cypress.com).

The MB95650L Series is a series of general-purpose, single-chip microcontrollers. In addition to a compact instruction set, the microcontrollers of this series contain a variety of peripheral functions.

## Features

### F<sup>2</sup>MC-8FX CPU core

Instruction set optimized for controllers

- Multiplication and division instructions
- 16-bit arithmetic operations
- Bit test branch instructions
- Bit manipulation instructions, etc.

### Clock

- Selectable main clock source
  - Main oscillation clock (up to 16.25 MHz, maximum machine clock frequency: 8.125 MHz)
  - External clock (up to 32.5 MHz, maximum machine clock frequency: 16.25 MHz)
  - Main CR clock (4 MHz ±2%)
  - Main CR PLL clock
    - The main CR PLL clock frequency becomes 8 MHz ±2% when the PLL multiplication rate is 2.
    - The main CR PLL clock frequency becomes 10 MHz ±2% when the PLL multiplication rate is 2.5.
    - The main CR PLL clock frequency becomes 12 MHz ±2% when the PLL multiplication rate is 3.
    - The main CR PLL clock frequency becomes 16 MHz ±2% when the PLL multiplication rate is 4.
  - Main PLL clock (maximum machine clock frequency: 16 MHz)
- Selectable subclock source
  - Suboscillation clock (32.768 kHz)
  - External clock (32.768 kHz)
  - Sub-CR clock (Typ: 100 kHz, Min: 50 kHz, Max: 150 kHz)

### Timer

- 8/16-bit composite timer × 2 channels
- Time-base timer × 1 channel
- Watch prescaler × 1 channel

### UART/SIO × 1 channel (The channel can be used either as a UART/SIO channel or as an I<sup>2</sup>C bus interface channel.)

- The function of this channel can be switched between UART/SIO and I<sup>2</sup>C bus interface.
- Full duplex double buffer
- Capable of clock asynchronous (UART) serial data transfer and clock synchronous (SIO) serial data transfer

### I<sup>2</sup>C bus interface × 2 channels (One of the two channels can be used either as an I<sup>2</sup>C bus interface channel or as a UART/SIO channel.)

- Supports Standard-mode and Fast-mode (400 kHz).
- Built-in wake-up function

### LIN-UART

- Full duplex double buffer
- Capable of clock asynchronous serial data transfer and clock synchronous serial data transfer

### External interrupt × 6 channels

- Interrupt by edge detection (rising edge, falling edge, and both edges can be selected)
- Can be used to wake up the device from different low power consumption (standby) modes

### 8/12-bit A/D converter × 6 channels

8-bit or 12-bit resolution can be selected.

### Low power consumption (standby) modes

There are four standby modes as follows:

- Stop mode
- Sleep mode
- Watch mode
- Time-base timer mode

### I/O port

- MB95F652E/F653E/F654E/F656E (number of I/O ports: 21)
  - General-purpose I/O ports (CMOS I/O) : 17
  - General-purpose I/O ports (N-ch open drain) : 4
- MB95F652L/F653L/F654L/F656L (number of I/O ports: 20)
  - General-purpose I/O ports (CMOS I/O) : 17
  - General-purpose I/O ports (N-ch open drain) : 3

### On-chip debug

- 1-wire serial control
- Serial writing supported (asynchronous mode)

### Hardware/software watchdog timer

- Built-in hardware watchdog timer
- Built-in software watchdog timer

**Power-on reset**

A power-on reset is generated when the power is switched on.

**Low-voltage detection reset circuit and low-voltage detection interrupt circuit (only available on MB95F652E/F653E/F654E/F656E)**

Built-in low-voltage detection function

**Clock supervisor counter**

Built-in clock supervisor counter

**Dual operation Flash memory**

The program/erase operation and the read operation can be executed in different banks (upper bank/lower bank) simultaneously.

**Flash memory security function**

Protects the content of the Flash memory.

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**1. Product Line-up**

Part number	MB95F652E	MB95F653E	MB95F654E	MB95F656E	MB95F652L	MB95F653L	MB95F654L	MB95F656L
<b>Parameter</b>								
Type	Flash memory product							
Clock supervisor counter	It supervises the main clock oscillation and the subclock oscillation.							
Flash memory capacity	8 Kbyte	12 Kbyte	20 Kbyte	36 Kbyte	8 Kbyte	12 Kbyte	20 Kbyte	36 Kbyte
RAM capacity	256 bytes	512 bytes	1024 bytes	1024 bytes	256 bytes	512 bytes	1024 bytes	1024 bytes
Power-on reset	Yes							
Low-voltage detection reset	Yes				No			
Reset input	Selected through software				With dedicated reset input			
CPU functions	<ul style="list-style-type: none"> <li>• Number of basic instructions : 136</li> <li>• Instruction bit length : 8 bits</li> <li>• Instruction length : 1 to 3 bytes</li> <li>• Data bit length : 1, 8 and 16 bits</li> <li>• Minimum instruction execution time : 61.5 ns (machine clock frequency = 16.25 MHz)</li> <li>• Interrupt processing time : 0.6 μs (machine clock frequency = 16.25 MHz)</li> </ul>							
General-purpose I/O	<ul style="list-style-type: none"> <li>• I/O port : 21</li> <li>• CMOS I/O : 17</li> <li>• N-ch open drain : 4</li> </ul>				<ul style="list-style-type: none"> <li>• I/O port : 20</li> <li>• CMOS I/O : 17</li> <li>• N-ch open drain : 3</li> </ul>			
Time-base timer	Interval time: 0.256 ms to 8.3 s (external clock frequency = 4 MHz)							
Hardware/software watchdog timer	<ul style="list-style-type: none"> <li>• Reset generation cycle Main oscillation clock at 10 MHz: 105 ms (Min)</li> <li>• The sub-CR clock can be used as the source clock of the software watchdog timer.</li> </ul>							
Wild register	It can be used to replace 3 bytes of data.							
LIN-UART	<ul style="list-style-type: none"> <li>• A wide range of communication speed can be selected by a dedicated reload timer.</li> <li>• It has a full duplex double buffer.</li> <li>• Both clock synchronous serial data transfer and clock asynchronous serial data transfer are enabled.</li> <li>• The LIN function can be used as a LIN master or a LIN slave.</li> </ul>							
8/12-bit A/D converter	6 channels 8-bit or 12-bit resolution can be selected.							
8/16-bit composite timer	2 channels <ul style="list-style-type: none"> <li>• The timer can be configured as an “8-bit timer × 2 channels” or a “16-bit timer × 1 channel”.</li> <li>• It has the following functions: interval timer function, PWC function, PWM function and input capture function.</li> <li>• Count clock: it can be selected from internal clocks (seven types) and external clocks.</li> <li>• It can output square wave.</li> </ul>							
External interrupt	6 channels <ul style="list-style-type: none"> <li>• Interrupt by edge detection (The rising edge, falling edge, and both edges can be selected.)</li> <li>• It can be used to wake up the device from different standby modes.</li> </ul>							
On-chip debug	<ul style="list-style-type: none"> <li>• 1-wire serial control</li> <li>• It supports serial writing (asynchronous mode).</li> </ul>							

*(Continued)*

(Continued)

Part number	MB95F652E	MB95F653E	MB95F654E	MB95F656E	MB95F652L	MB95F653L	MB95F654L	MB95F656L								
Parameter																
UART/SIO	1 channel (The channel can be used either as a UART/SIO channel or as an I <sup>2</sup> C bus interface channel.) <ul style="list-style-type: none"> <li>Data transfer with UART/SIO is enabled.</li> <li>It has a full duplex double buffer, variable data length (5/6/7/8 bits), an internal baud rate generator and an error detection function.</li> <li>It uses the NRZ type transfer format.</li> <li>LSB-first data transfer and MSB-first data transfer are available to use.</li> <li>Both clock asynchronous (UART) serial data transfer and clock synchronous (SIO) serial data transfer are enabled.</li> </ul>															
I <sup>2</sup> C bus interface	2 channels (One of the two channels can be used either as an I <sup>2</sup> C bus interface channel or as a UART/SIO channel.) <ul style="list-style-type: none"> <li>Master/slave transmission and reception</li> <li>It has the following functions: bus error function, arbitration function, transmission direction detection function, wake-up function, and functions of generating and detecting repeated START conditions.</li> </ul>															
Watch prescaler	Eight different time intervals can be selected.															
Flash memory	<ul style="list-style-type: none"> <li>It supports automatic programming (Embedded Algorithm), and program/erase/erase-suspend/erase-resume commands.</li> <li>It has a flag indicating the completion of the operation of Embedded Algorithm.</li> <li>Flash security feature for protecting the content of the Flash memory</li> </ul> <table border="1" data-bbox="350 1014 1255 1083"> <tr> <td>Number of program/erase cycles</td> <td>1000</td> <td>10000</td> <td>100000</td> </tr> <tr> <td>Data retention time</td> <td>20 years</td> <td>10 years</td> <td>5 years</td> </tr> </table>								Number of program/erase cycles	1000	10000	100000	Data retention time	20 years	10 years	5 years
Number of program/erase cycles	1000	10000	100000													
Data retention time	20 years	10 years	5 years													
Standby mode	There are four standby modes as follows: <ul style="list-style-type: none"> <li>Stop mode</li> <li>Sleep mode</li> <li>Watch mode</li> <li>Time-base timer mode</li> </ul>															
Package	FPT-24P-M10 FPT-24P-M34 LCC-32P-M19															

**2. Packages and Corresponding Products**

<b>Part number</b>	<b>MB95F652E</b>	<b>MB95F653E</b>	<b>MB95F654E</b>	<b>MB95F656E</b>	<b>MB95F652L</b>	<b>MB95F653L</b>	<b>MB95F654L</b>	<b>MB95F656L</b>
<b>Package</b>								
FPT-24P-M10	O	O	O	O	O	O	O	O
FPT-24P-M34	O	O	O	O	O	O	O	O
LCC-32P-M19	O	O	O	O	O	O	O	O

O: Available



### **3. Differences among Products and Notes on Product Selection**

#### **Current consumption**

When using the on-chip debug function, take account of the current consumption of Flash memory program/erase.

For details of current consumption, see “18. Electrical Characteristics”.

#### **Package**

For details of information on each package, see “2. Packages and Corresponding Products” and “22. Package Dimension”.

#### **Operating voltage**

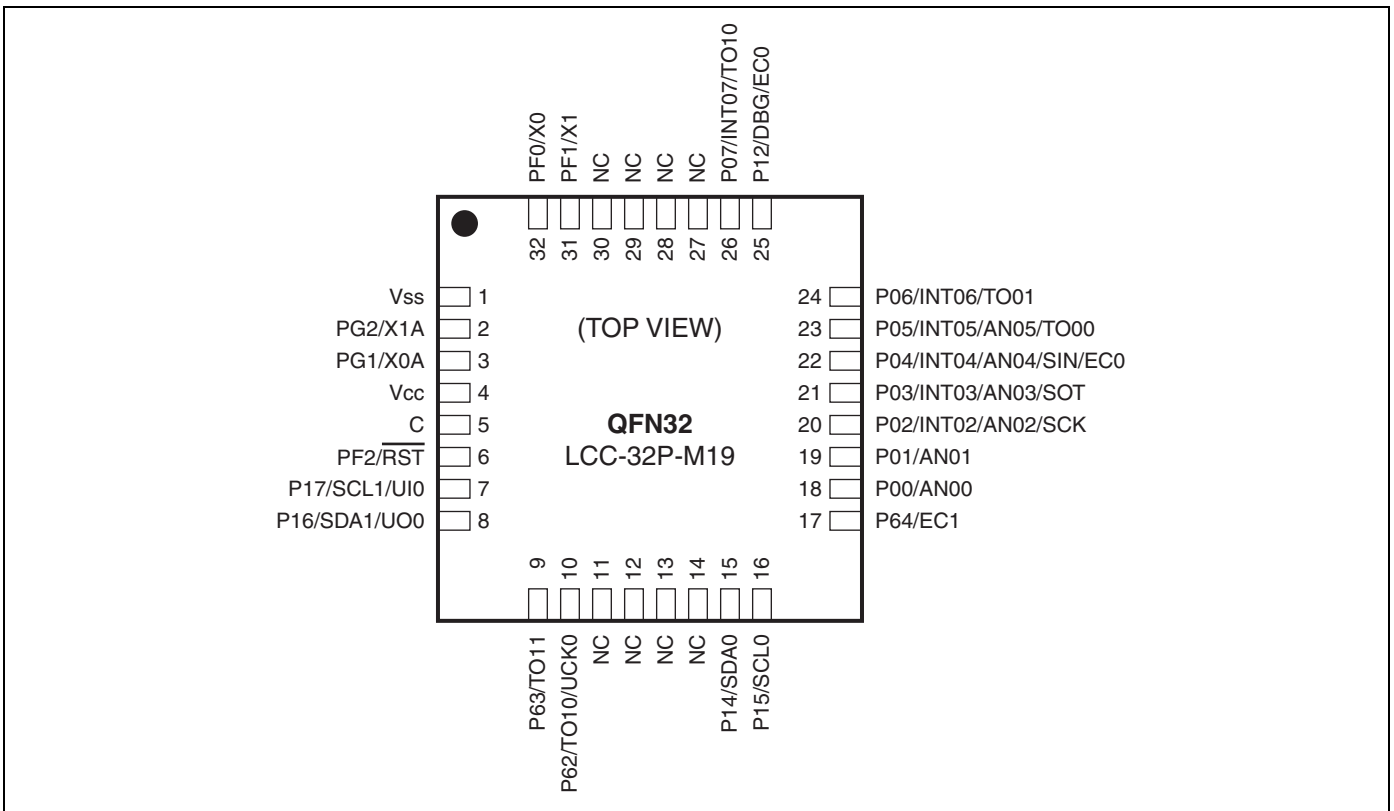
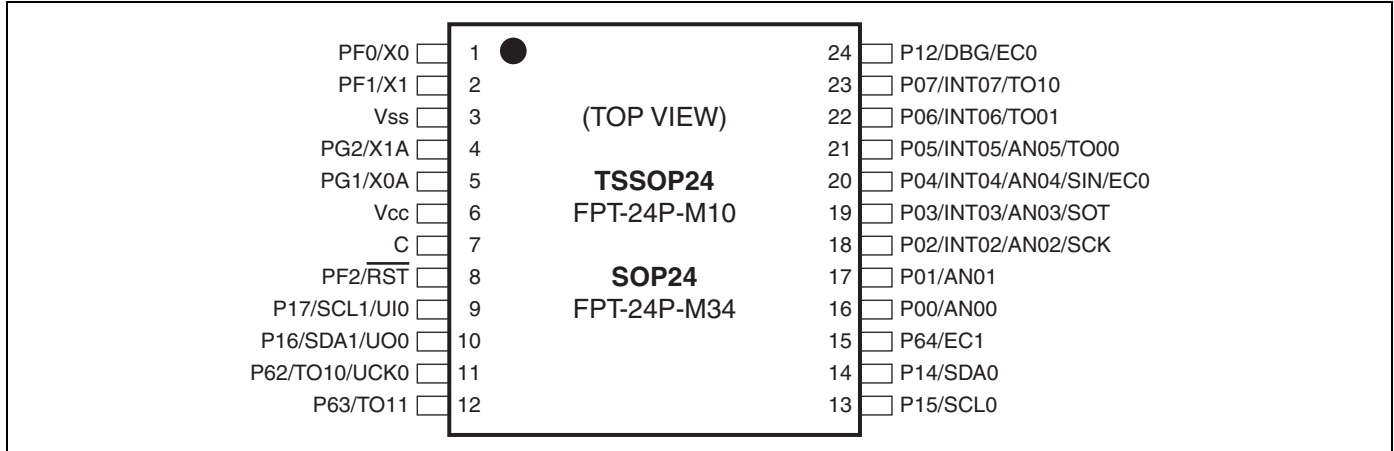
The operating voltage varies, depending on whether the on-chip debug function is used or not.

For details of operating voltage, see “18. Electrical Characteristics”.

#### **On-chip debug function**

The on-chip debug function requires that  $V_{CC}$ ,  $V_{SS}$  and one serial wire be connected to an evaluation tool. For details of the connection method, refer to “Chapter 20 Example Of Serial Programming Connection” in “New 8FX MB95650L Series Hardware Manual”.

**4. Pin Assignment**



**5. Pin Functions**

Pin no.		Pin name	I/O circuit type*4	Function	I/O type			
SOP24*1, TSSOP24*2	QFN32*3				Input	Output	OD*5	PU*6
1	32	PF0	B	General-purpose I/O port	Hysteresis	CMOS	—	—
		X0		Main clock input oscillation pin				
2	31	PF1	B	General-purpose I/O port	Hysteresis	CMOS	—	—
		X1		Main clock I/O oscillation pin				
3	1	V <sub>SS</sub>	—	Power supply pin (GND)	—	—	—	—
4	2	PG2	C	General-purpose I/O port	Hysteresis	CMOS	—	0
		X1A		Subclock I/O oscillation pin				
5	3	PG1	C	General-purpose I/O port	Hysteresis	CMOS	—	0
		X0A		Subclock input oscillation pin				
6	4	V <sub>CC</sub>	—	Power supply pin	—	—	—	—
7	5	C	—	Decoupling capacitor connection pin	—	—	—	—
8	6	PF2	A	General-purpose I/O port	Hysteresis	CMOS	0	—
		$\overline{\text{RST}}$		Reset pin Dedicated reset pin on MB95F652L/F653L/F654L/F656L				
9	7	P17	J	General-purpose I/O port	CMOS	CMOS	—/0*7	—
		SCL1		I <sup>2</sup> C bus interface ch. 1 clock I/O pin				
		UI0		UART/SIO ch. 0 data input pin				
10	8	P16	J	General-purpose I/O port	CMOS	CMOS	—/0*7	—
		SDA1		I <sup>2</sup> C bus interface ch. 1 data I/O pin				
		UO0		UART/SIO ch. 0 data output pin				
11	10	P62	D	General-purpose I/O port High-current pin	Hysteresis	CMOS	—	0
		TO10		8/16-bit composite timer ch. 1 output pin				
		UCK0		UART/SIO ch. 0 clock I/O pin				
12	9	P63	D	General-purpose I/O port High-current output	Hysteresis	CMOS	—	0
		TO11		8/16-bit composite timer ch. 1 output pin				
13	16	P15	I	General-purpose I/O port	CMOS	CMOS	0	—
		SCL0		I <sup>2</sup> C bus interface ch. 0 clock I/O pin				
14	15	P14	I	General-purpose I/O port	CMOS	CMOS	0	—
		SDA0		I <sup>2</sup> C bus interface ch. 0 data I/O pin				
15	17	P64	D	General-purpose I/O port	Hysteresis	CMOS	—	0
		EC1		8/16-bit composite timer ch. 1 clock input pin				

*(Continued)*

Pin no.		Pin name	I/O circuit type*4	Function	I/O type			
SOP24*1, TSSOP24*2	QFN32*3				Input	Output	OD*5	PU*6
16	18	P00	E	General-purpose I/O port	Hysteresis/ analog	CMOS	—	0
		AN00		8/12-bit A/D converter analog input pin				
17	18	P01	E	General-purpose I/O port	Hysteresis/ analog	CMOS	—	0
		AN01		8/12-bit A/D converter analog input pin				
18	20	P02	E	General-purpose I/O port	Hysteresis/ analog	CMOS	—	0
		INT02		External interrupt input pin				
		AN02		8/12-bit A/D converter analog input pin				
		SCK		LIN-UART clock I/O pin				
19	21	P03	E	General-purpose I/O port	Hysteresis/ analog	CMOS	—	0
		INT03		External interrupt input pin				
		AN03		8/12-bit A/D converter analog input pin				
		SOT		LIN-UART data output pin				
20	22	P04	F	General-purpose I/O port	CMOS/ analog	CMOS	—	0
		INT04		External interrupt input pin				
		AN04		8/12-bit A/D converter analog input pin				
		SIN		LIN-UART data input pin				
		EC0		8/16-bit composite timer ch. 0 clock input pin				
21	23	P05	K	General-purpose I/O port High-current pin	Hysteresis/ analog	CMOS	—	0
		INT05		External interrupt input pin				
		AN05		8/12-bit A/D converter analog input pin				
		TO00		8/16-bit composite timer ch. 0 output pin				
22	24	P06	D	General-purpose I/O port High-current pin	Hysteresis	CMOS	—	0
		INT06		External interrupt input pin				
		TO01		8/16-bit composite timer ch. 0 output pin				
23	26	P07	K	General-purpose I/O port High-current pin	Hysteresis	CMOS	—	0
		INT07		External interrupt input pin				
		TO10		8/16-bit composite timer ch. 1 output pin				

*(Continued)*

(Continued)

Pin no.		Pin name	I/O circuit type*4	Function	I/O type			
SOP24*1, TSSOP24*2	QFN32*3				Input	Output	OD*5	PU*6
24	25	P12	H	General-purpose I/O port	Hysteresis	CMOS	O	—
		DBG		DBG input pin				
		EC0		8/16-bit composite timer ch. 0 clock input pin				
—	11	NC	—	It is an internally connected pin. Always leave it unconnected.	—	—	—	—
	12							
	13							
	14							
	27							
	28							
	29							
30								

O: Available

\*1: FPT-24P-M34

\*2: FPT-24P-M10

\*3: LCC-32P-M19

\*4: For the I/O circuit types, see "6. I/O Circuit Type".

\*5: N-ch open drain

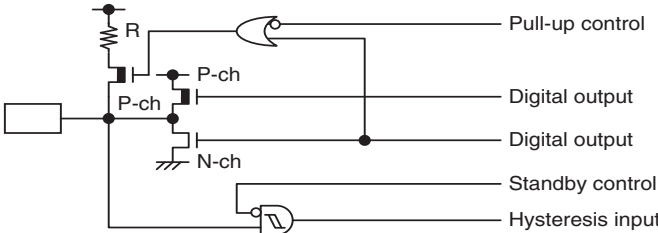
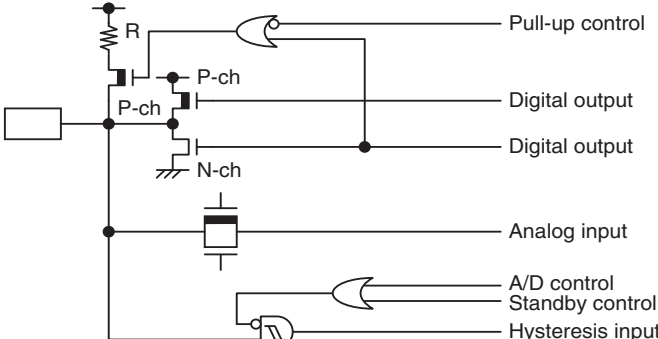
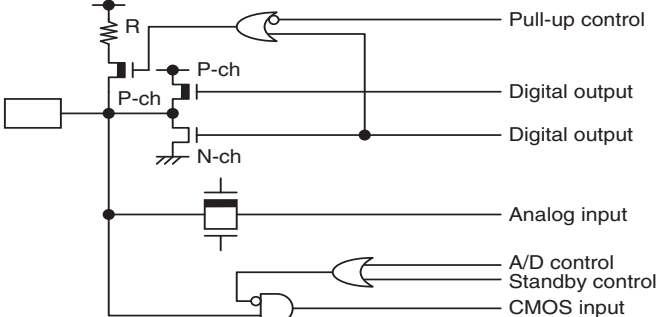
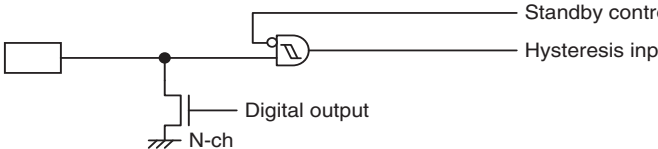
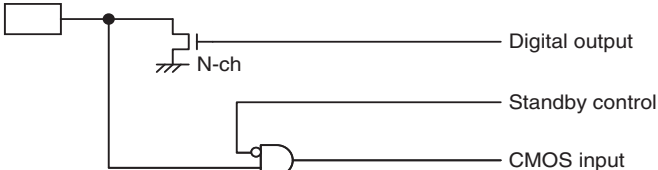
\*6: Pull-up

\*7: In I<sup>2</sup>C mode, the pin becomes an N-ch open drain pin.

**6. I/O Circuit Type**

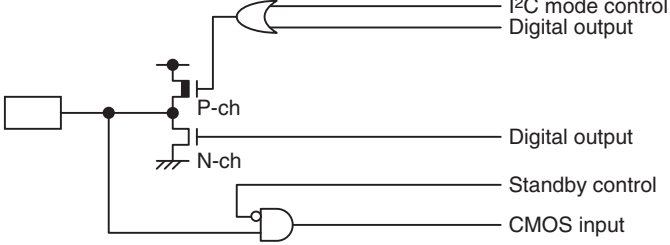
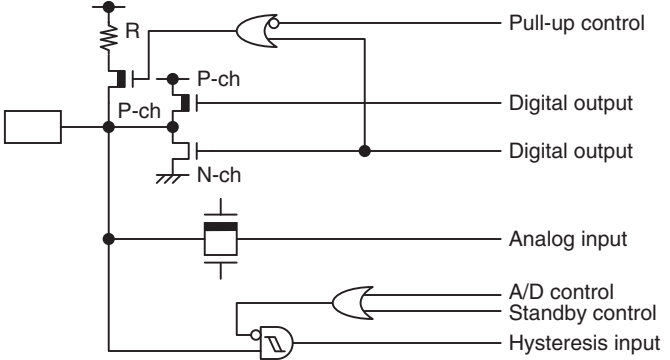
Type	Circuit	Remarks
A		<ul style="list-style-type: none"> <li>• N-ch open drain output</li> <li>• Hysteresis input</li> <li>• Reset output</li> </ul>
B		<ul style="list-style-type: none"> <li>• Oscillation circuit</li> <li>• High-speed side Feedback resistance: approx. 1 MΩ</li> <li>• CMOS output</li> <li>• Hysteresis input</li> </ul>
C		<ul style="list-style-type: none"> <li>• Oscillation circuit</li> <li>• Low-speed side Feedback resistance: approx. 5 MΩ</li> <li>• CMOS output</li> <li>• Hysteresis input</li> <li>• Pull-up control</li> </ul>

*(Continued)*

Type	Circuit	Remarks
D		<ul style="list-style-type: none"> <li>• CMOS output</li> <li>• Hysteresis input</li> <li>• Pull-up control</li> <li>• High current output</li> </ul>
E		<ul style="list-style-type: none"> <li>• CMOS output</li> <li>• Hysteresis input</li> <li>• Pull-up control</li> <li>• Analog input</li> </ul>
F		<ul style="list-style-type: none"> <li>• CMOS output</li> <li>• CMOS input</li> <li>• Pull-up control</li> <li>• Analog input</li> </ul>
H		<ul style="list-style-type: none"> <li>• N-ch open drain output</li> <li>• Hysteresis input</li> </ul>
I		<ul style="list-style-type: none"> <li>• N-ch open drain output</li> <li>• CMOS input</li> </ul>

(Continued)

(Continued)

Type	Circuit	Remarks
J	 <p>The diagram for Type J shows a circuit with a P-channel MOSFET and an N-channel MOSFET. The P-channel MOSFET's gate is connected to an OR gate with inputs from 'I<sup>2</sup>C mode control' and 'Digital output'. Its source is connected to a pull-up resistor and its drain is connected to the output node. The N-channel MOSFET's gate is connected to an AND gate with inputs from 'Standby control' and 'CMOS input'. Its source is connected to ground and its drain is connected to the output node. The output node is also connected to a 'Digital output' terminal.</p>	<ul style="list-style-type: none"> <li>• CMOS output</li> <li>• CMOS input</li> <li>• N-ch open drain output in I<sup>2</sup>C mode</li> </ul>
K	 <p>The diagram for Type K shows a more complex circuit. It includes a pull-up resistor 'R' connected to the output node. The output node is connected to two 'Digital output' terminals. The circuit features two P-channel MOSFETs and one N-channel MOSFET. The gates of the P-channel MOSFETs are connected to an OR gate with inputs from 'Pull-up control' and 'Digital output'. The gates of the N-channel MOSFETs are connected to an AND gate with inputs from 'A/D control' and 'Standby control'. The output node is also connected to an 'Analog input' terminal and a 'Hysteresis input' terminal.</p>	<ul style="list-style-type: none"> <li>• CMOS output</li> <li>• Hysteresis input</li> <li>• Pull-up control</li> <li>• Analog input</li> <li>• High current output</li> </ul>



## 7. Handling Precautions

Any semiconductor devices have inherently a certain rate of failure. The possibility of failure is greatly affected by the conditions in which they are used (circuit conditions, environmental conditions, etc.). This page describes precautions that must be observed to minimize the chance of failure and to obtain higher reliability from your Cypress semiconductor devices.

### 7.1 Precautions for Product Design

This section describes precautions when designing electronic equipment using semiconductor devices.

#### Absolute Maximum Ratings

Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of certain established limits, called absolute maximum ratings. Do not exceed these ratings.

#### Recommended Operating Conditions

Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their sales representative beforehand.

#### Processing and Protection of Pins

These precautions must be followed when handling the pins which connect semiconductor devices to power supply and input/output functions.

##### 1. Preventing Over-Voltage and Over-Current Conditions

Exposure to voltage or current levels in excess of maximum ratings at any pin is likely to cause deterioration within the device, and in extreme cases leads to permanent damage of the device. Try to prevent such overvoltage or over-current conditions at the design stage.

##### 2. Protection of Output Pins

Shorting of output pins to supply pins or other output pins, or connection to large capacitance can cause large current flows. Such conditions if present for extended periods of time can damage the device.

Therefore, avoid this type of connection.

##### 3. Handling of Unused Input Pins

Unconnected input pins with very high impedance levels can adversely affect stability of operation. Such pins should be connected through an appropriate resistance to a power supply pin or ground pin.

#### Latch-up

Semiconductor devices are constructed by the formation of P-type and N-type areas on a substrate. When subjected to abnormally high voltages, internal parasitic PNPN junctions (called thyristor structures) may be formed, causing large current levels in excess of several hundred mA to flow continuously at the power supply pin. This condition is called latch-up.

**CAUTION:** The occurrence of latch-up not only causes loss of reliability in the semiconductor device, but can cause injury or damage from high heat, smoke or flame. To prevent this from happening, do the following:

1. Be sure that voltages applied to pins do not exceed the absolute maximum ratings. This should include attention to abnormal noise, surge levels, etc.
2. Be sure that abnormal current flows do not occur during the power-on sequence.

#### Observance of Safety Regulations and Standards

Most countries in the world have established standards and regulations regarding safety, protection from electromagnetic interference, etc. Customers are requested to observe applicable regulations and standards in the design of products.

#### Fail-Safe Design

Any semiconductor devices have inherently a certain rate of failure. You must protect against injury, damage or loss from such failures by incorporating safety design measures into your facility and equipment such as redundancy, fire protection, and prevention of over-current levels and other abnormal operating conditions.

## Precautions Related to Usage of Devices

Cypress semiconductor devices are intended for use in standard applications (computers, office automation and other office equipment, industrial, communications, and measurement equipment, personal or household devices, etc.).

**CAUTION:** Customers considering the use of our products in special applications where failure or abnormal operation may directly affect human lives or cause physical injury or property damage, or where extremely high levels of reliability are demanded (such as aerospace systems, atomic energy controls, sea floor repeaters, vehicle operating controls, medical devices for life support, etc.) are requested to consult with sales representatives before such use. The company will not be responsible for damages arising from such use without prior approval.

## 7.2 Precautions for Package Mounting

Package mounting may be either lead insertion type or surface mount type. In either case, for heat resistance during soldering, you should only mount under Cypress's recommended conditions. For detailed information about mount conditions, contact your sales representative.

### Lead Insertion Type

Mounting of lead insertion type packages onto printed circuit boards may be done by two methods: direct soldering on the board, or mounting by using a socket.

Direct mounting onto boards normally involves processes for inserting leads into through-holes on the board and using the flow soldering (wave soldering) method of applying liquid solder. In this case, the soldering process usually causes leads to be subjected to thermal stress in excess of the absolute ratings for storage temperature. Mounting processes should conform to Cypress recommended mounting conditions.

If socket mounting is used, differences in surface treatment of the socket contacts and IC lead surfaces can lead to contact deterioration after long periods. For this reason it is recommended that the surface treatment of socket contacts and IC leads be verified before mounting.

### Surface Mount Type

Surface mount packaging has longer and thinner leads than lead-insertion packaging, and therefore leads are more easily deformed or bent. The use of packages with higher pin counts and narrower pin pitch results in increased susceptibility to open connections caused by deformed pins, or shorting due to solder bridges.

You must use appropriate mounting techniques. Cypress recommends the solder reflow method, and has established a ranking of mounting conditions for each product. Users are advised to mount packages in accordance with Cypress ranking of recommended conditions.

### Lead-Free Packaging

**CAUTION:** When ball grid array (BGA) packages with Sn-Ag-Cu balls are mounted using Sn-Pb eutectic soldering, junction strength may be reduced under some conditions of use.

### Storage of Semiconductor Devices

Because plastic chip packages are formed from plastic resins, exposure to natural environmental conditions will cause absorption of moisture. During mounting, the application of heat to a package that has absorbed moisture can cause surfaces to peel, reducing moisture resistance and causing packages to crack. To prevent, do the following:

1. Avoid exposure to rapid temperature changes, which cause moisture to condense inside the product. Store products in locations where temperature changes are slight.
2. Use dry boxes for product storage. Products should be stored below 70% relative humidity, and at temperatures between 5°C and 30°C.  
When you open Dry Package that recommends humidity 40% to 70% relative humidity.
3. When necessary, Cypress packages semiconductor devices in highly moisture-resistant aluminum laminate bags, with a silica gel desiccant. Devices should be sealed in their aluminum laminate bags for storage.
4. Avoid storing packages where they are exposed to corrosive gases or high levels of dust.

### Baking

Packages that have absorbed moisture may be de-moisturized by baking (heat drying). Follow the Cypress recommended conditions for baking.

Condition: 125°C/24 h

### **Static Electricity**

Because semiconductor devices are particularly susceptible to damage by static electricity, you must take the following precautions:

1. Maintain relative humidity in the working environment between 40% and 70%.  
Use of an apparatus for ion generation may be needed to remove electricity.
2. Electrically ground all conveyors, solder vessels, soldering irons and peripheral equipment.
3. Eliminate static body electricity by the use of rings or bracelets connected to ground through high resistance (on the level of 1 MΩ).  
Wearing of conductive clothing and shoes, use of conductive floor mats and other measures to minimize shock loads is recommended.
4. Ground all fixtures and instruments, or protect with anti-static measures.
5. Avoid the use of styrofoam or other highly static-prone materials for storage of completed board assemblies.

### **7.3 Precautions for Use Environment**

Reliability of semiconductor devices depends on ambient temperature and other conditions as described above.

For reliable performance, do the following:

1. Humidity  
Prolonged use in high humidity can lead to leakage in devices as well as printed circuit boards. If high humidity levels are anticipated, consider anti-humidity processing.
2. Discharge of Static Electricity  
When high-voltage charges exist close to semiconductor devices, discharges can cause abnormal operation. In such cases, use anti-static measures or processing to prevent discharges.
3. Corrosive Gases, Dust, or Oil  
Exposure to corrosive gases or contact with dust or oil may lead to chemical reactions that will adversely affect the device. If you use devices in such conditions, consider ways to prevent such exposure or to protect the devices.
4. Radiation, Including Cosmic Radiation  
Most devices are not designed for environments involving exposure to radiation or cosmic radiation. Users should provide shielding as appropriate.
5. Smoke, Flame  
**CAUTION:** Plastic molded devices are flammable, and therefore should not be used near combustible substances. If devices begin to smoke or burn, there is danger of the release of toxic gases.

Customers considering the use of Cypress products in other special environmental conditions should consult with sales representatives.

## 8. Notes On Device Handling

### Preventing latch-ups

When using the device, ensure that the voltage applied does not exceed the maximum voltage rating.

In a CMOS IC, if a voltage higher than  $V_{CC}$  or a voltage lower than  $V_{SS}$  is applied to an input/output pin that is neither a medium-withstand voltage pin nor a high-withstand voltage pin, or if a voltage out of the rating range of power supply voltage mentioned in “18.1 Absolute Maximum Ratings” of “18. Electrical Characteristics” is applied to the  $V_{CC}$  pin or the  $V_{SS}$  pin, a latch-up may occur.

When a latch-up occurs, power supply current increases significantly, which may cause a component to be thermally destroyed.

### Stabilizing supply voltage

Supply voltage must be stabilized.

A malfunction may occur when power supply voltage fluctuates rapidly even though the fluctuation is within the guaranteed operating range of the  $V_{CC}$  power supply voltage.

As a rule of voltage stabilization, suppress voltage fluctuation so that the fluctuation in  $V_{CC}$  ripple (p-p value) at the commercial frequency (50 Hz/60 Hz) does not exceed 10% of the standard  $V_{CC}$  value, and the transient fluctuation rate does not exceed 0.1 V/ms at a momentary fluctuation such as switching the power supply.

### Notes on using the external clock

When an external clock is used, oscillation stabilization wait time is required for power-on reset, wake-up from subclock mode or stop mode.

## 9. Pin Connection

### Treatment of unused pins

If an unused input pin is left unconnected, a component may be permanently damaged due to malfunctions or latch-ups. Always pull up or pull down an unused input pin through a resistor of at least 2 k $\Omega$ . Set an unused input/output pin to the output state and leave it unconnected, or set it to the input state and treat it the same as an unused input pin. If there is an unused output pin, leave it unconnected.

### Power supply pins

To reduce unnecessary electro-magnetic emission, prevent malfunctions of strobe signals due to an increase in the ground level, and conform to the total output current standard, always connect the V<sub>CC</sub> pin and the V<sub>SS</sub> pin to the power supply and ground outside the device. In addition, connect the current supply source to the V<sub>CC</sub> pin and the V<sub>SS</sub> pin with low impedance.

It is also advisable to connect a ceramic capacitor of approximately 1.0  $\mu$ F as a bypass capacitor between the V<sub>CC</sub> pin and the V<sub>SS</sub> pin at a location close to this device.

### DBG pin

Connect the DBG pin to an external pull-up resistor of 2 k $\Omega$  or above.

After power-on, ensure that the DBG pin does not stay at “L” level until the reset output is released.

The DBG pin becomes a communication pin in debug mode. Since the actual pull-up resistance depends on the tool used and the interconnection length, refer to the tool document when selecting a pull-up resistor.

### RST pin

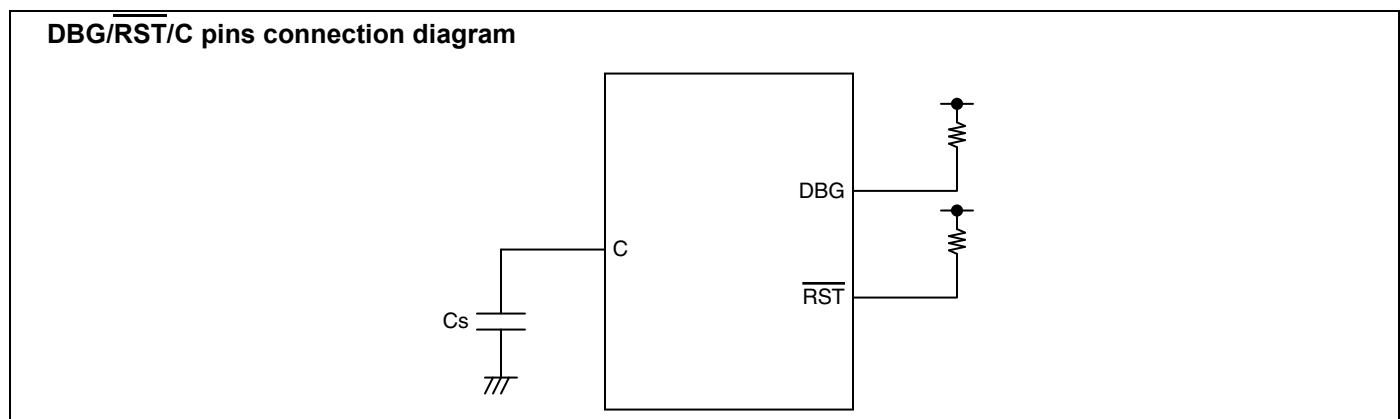
Connect the  $\overline{\text{RST}}$  pin to an external pull-up resistor of 2 k $\Omega$  or above.

To prevent the device from unintentionally entering the reset mode due to noise, minimize the interconnection length between a pull-up resistor and the  $\overline{\text{RST}}$  pin and that between a pull-up resistor and the V<sub>CC</sub> pin when designing the layout of the printed circuit board.

The PF2/ $\overline{\text{RST}}$  pin functions as the reset input/output pin after power-on. In addition, the reset output of the PF2/ $\overline{\text{RST}}$  pin can be enabled by the RSTOE bit in the SYSC register, and the reset input function and the general purpose I/O function can be selected by the RSTEN bit in the SYSC register.

### C pin

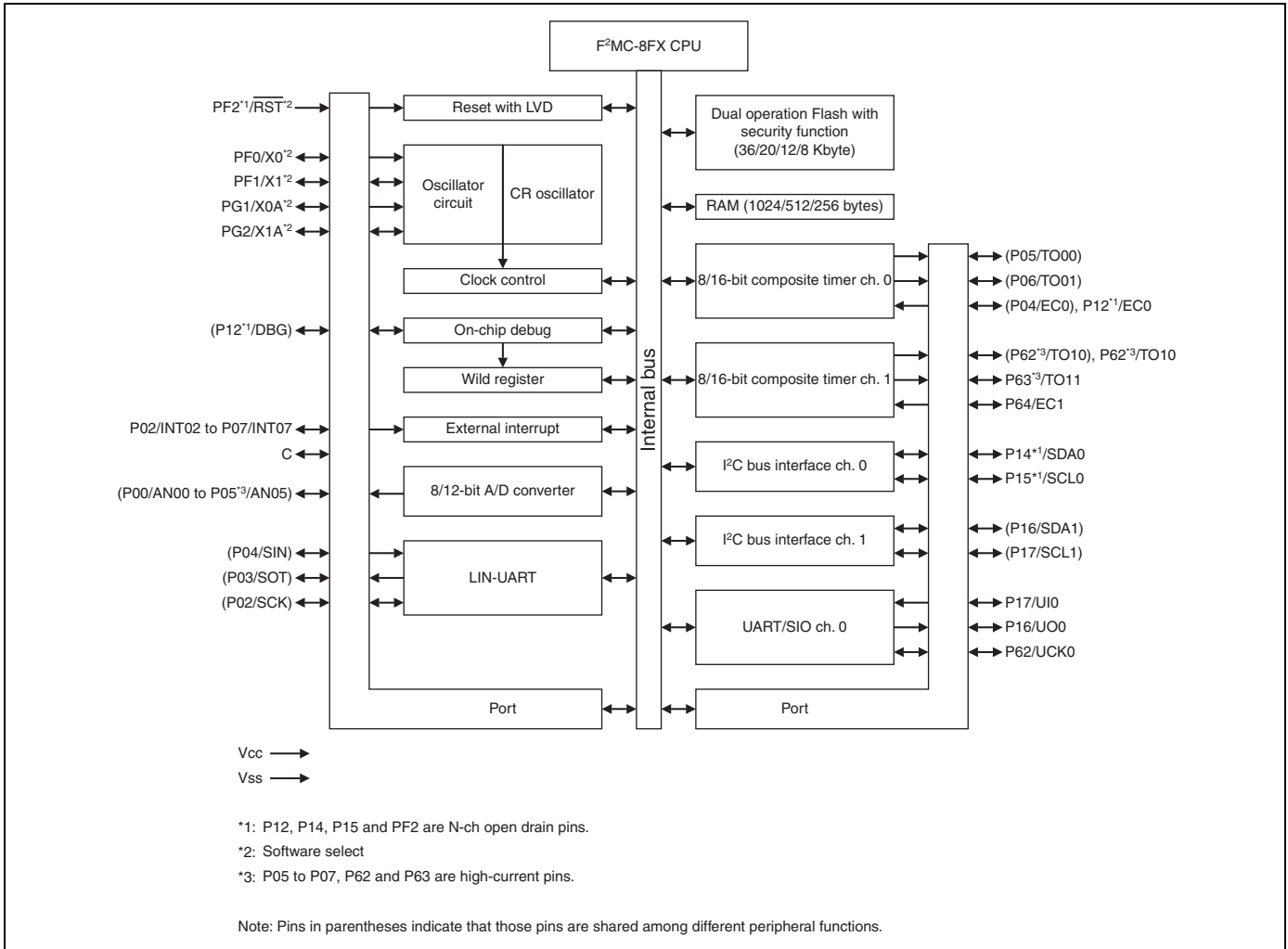
Use a ceramic capacitor or a capacitor with equivalent frequency characteristics. The decoupling capacitor for the V<sub>CC</sub> pin must have a capacitance equal to or larger than the capacitance of C<sub>S</sub>. For the connection to a decoupling capacitor C<sub>S</sub>, see the diagram below. To prevent the device from unintentionally entering a mode to which the device is not set to transit due to noise, minimize the distance between the C pin and C<sub>S</sub> and the distance between C<sub>S</sub> and the V<sub>SS</sub> pin when designing the layout of a printed circuit board.



### Note on serial communication

In serial communication, reception of wrong data may occur due to noise or other causes. Therefore, design a printed circuit board to prevent noise from occurring. Taking account of the reception of wrong data, take measures such as adding a checksum to the end of data in order to detect errors. If an error is detected, retransmit the data.

### 10. Block Diagram

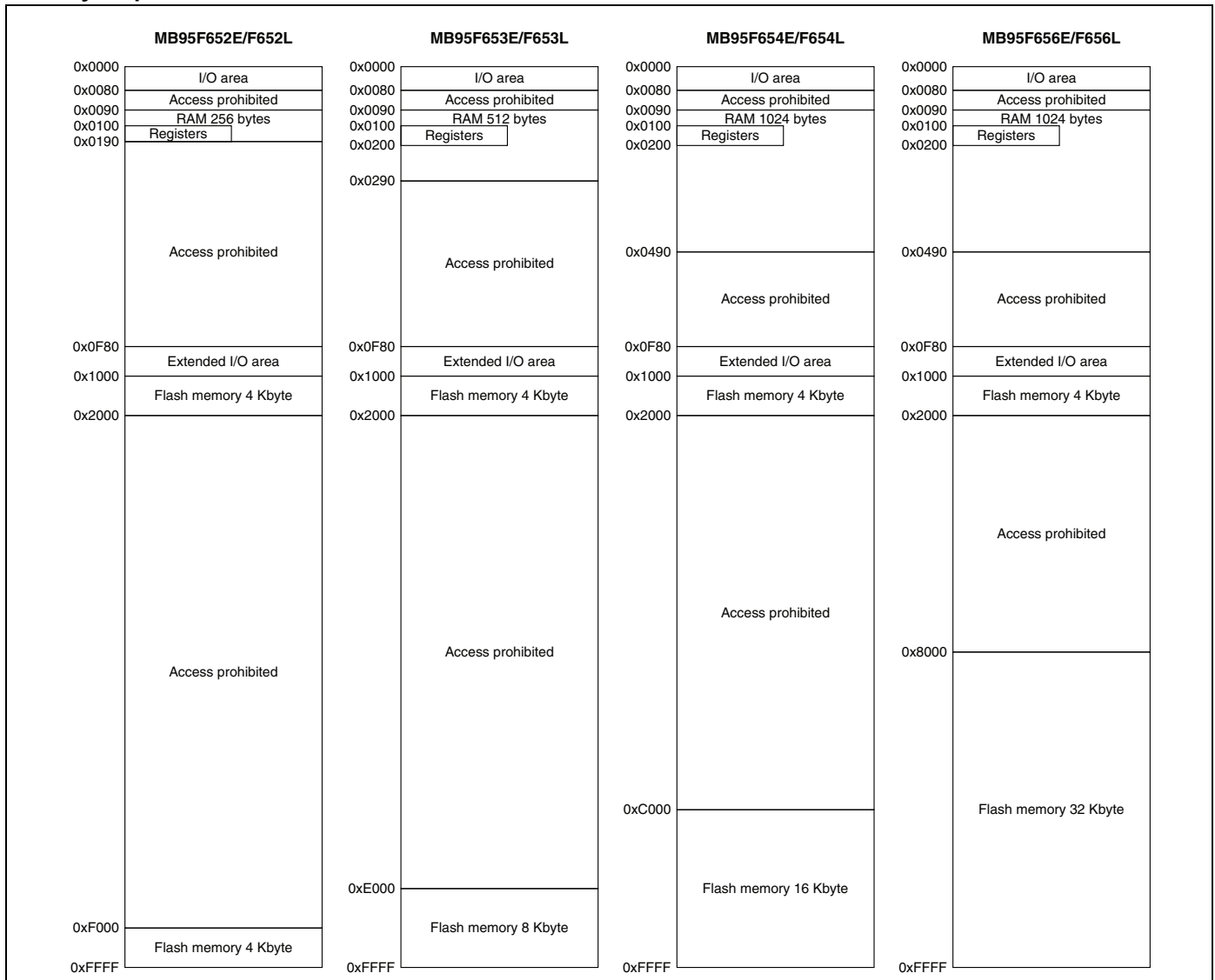


## 11. CPU Core

### Memory space

The memory space of the MB95650L Series is 64 Kbyte in size, and consists of an I/O area, an extended I/O area, a data area, and a program area. The memory space includes areas intended for specific purposes such as general-purpose registers and a vector table. The memory maps of the MB95650L Series are shown below.

### Memory maps



## 12. Memory Space

The memory space of the MB95650L Series is 64 Kbyte in size, and consists of an I/O area, an extended I/O area, a data area, and a program area. The memory space includes areas for specific applications such as general-purpose registers and a vector table.

### I/O area (addresses: 0x0000 to 0x007F)

- This area contains the control registers and data registers for built-in peripheral functions.
- As the I/O area forms part of the memory space, it can be accessed in the same way as the memory. It can also be accessed at high-speed by using direct addressing instructions.

### Extended I/O area (addresses: 0x0F80 to 0x0FFF)

- This area contains the control registers and data registers for built-in peripheral functions.
- As the extended I/O area forms part of the memory space, it can be accessed in the same way as the memory.

### Data area

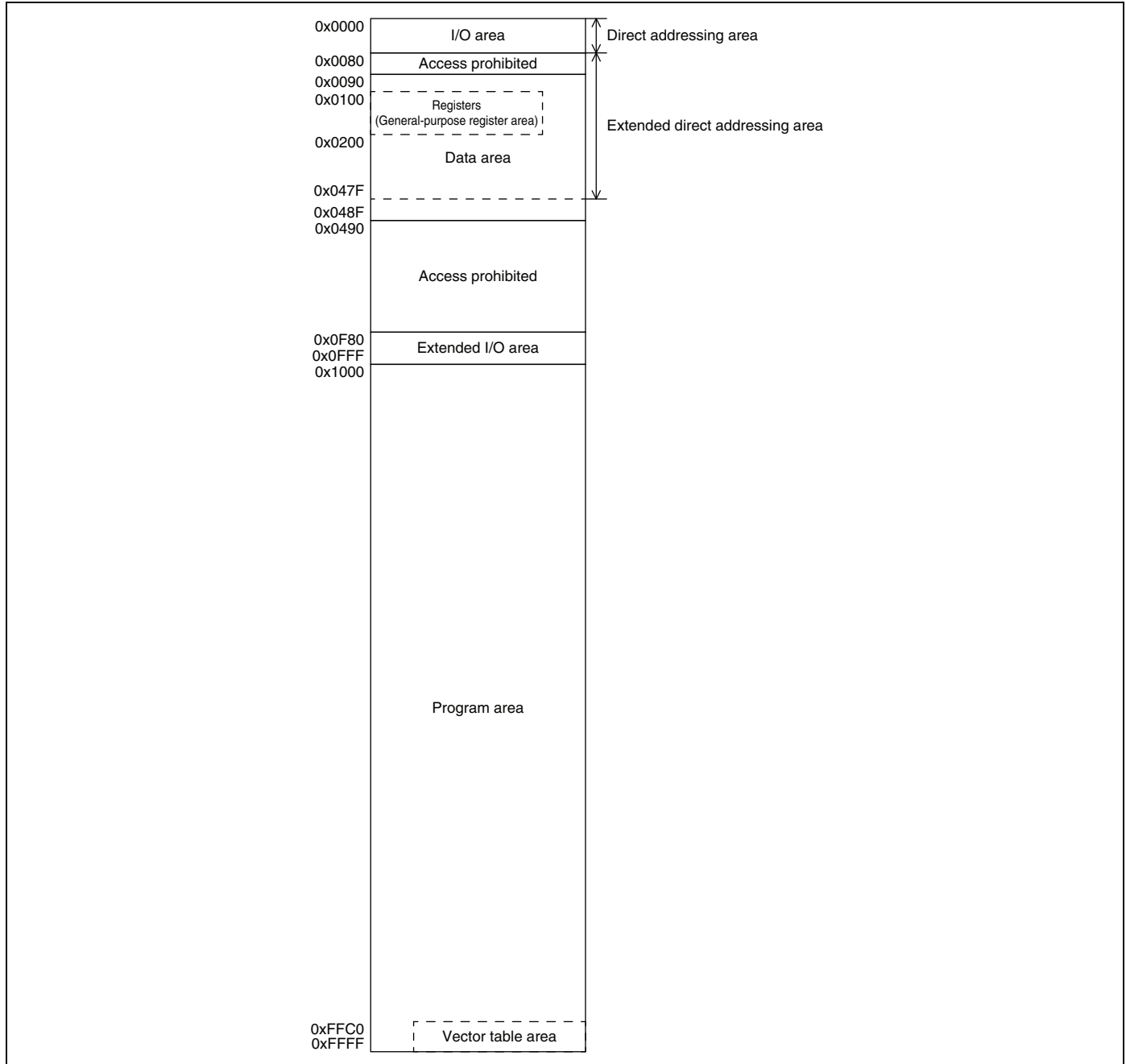
- Static RAM is incorporated in the data area as the internal data area.
- The internal RAM size varies according to product.
- The RAM area from 0x0090 to 0x00FF can be accessed at high-speed by using direct addressing instructions.
- In MB95F656E/F656L, the area from 0x0090 to 0x047F is an extended direct addressing area. It can be accessed at high-speed by direct addressing instructions with a direct bank pointer set.
- In MB95F654E/F654L, the area from 0x0090 to 0x047F is an extended direct addressing area. It can be accessed at high-speed by direct addressing instructions with a direct bank pointer set.
- In MB95F653E/F653L, the area from 0x0090 to 0x028F is an extended direct addressing area. It can be accessed at high-speed by direct addressing instructions with a direct bank pointer set.
- In MB95F652E/F652L, the area from 0x0090 to 0x018F is an extended direct addressing area. It can be accessed at high-speed by direct addressing instructions with a direct bank pointer set.
- In MB95F653E/F653L/F654E/F654L/F656E/F656L, the area from 0x0100 to 0x01FF can be used as a general-purpose register area.
- In MB95F652E/F652L, the area from 0x0100 to 0x018F can be used as a general-purpose register area.

### Program area

- The Flash memory is incorporated in the program area as the internal program area.
- The Flash memory size varies according to product.
- The area from 0xFFC0 to 0xFFFF is used as the vector table.
- The area from 0xFFBB to 0xFFBF is used to store data of the non-volatile register.



Memory space map



### 13. Areas for Specific Applications

The general-purpose register area and vector table area are used for the specific applications.

#### General-purpose register area (Addresses: 0x0100 to 0x01FF\*<sup>1</sup>)

- This area contains the auxiliary registers used for 8-bit arithmetic operations, transfer, etc.
- As this area forms part of the RAM area, it can also be used as conventional RAM.
- When the area is used as general-purpose registers, general-purpose register addressing enables high-speed access with short instructions.

#### Non-volatile register data area (Addresses: 0xFFBB to 0xFFBF)

- The area from 0xFFBB to 0xFFBF is used to store data of the non-volatile register. For details, refer to “Chapter 23 Non-volatile Register (NVR) Interface” in “New 8FX MB95650L Series Hardware Manual”.

#### Vector table area (Addresses: 0xFFC0 to 0xFFFF)

- This area is used as the vector table for vector call instructions (CALLV), interrupts, and resets.
- The top of the Flash memory area is allocated to the vector table area. The start address of a service routine is set to an address in the vector table in the form of data.

“16. Interrupt Source Table” lists the vector table addresses corresponding to vector call instructions, interrupts, and resets.

For details, refer to “Chapter 4 Reset”, “Chapter 5 Interrupts” and “A.2 Special Instruction Special Instruction CALLV #vct” in “New 8FX MB95650L Series Hardware Manual”.

#### Direct bank pointer and access area

Direct bank pointer (DP[2:0])	Operand-specified dir	Access area
0bXXX (It does not affect mapping.)	0x0000 to 0x007F	0x0000 to 0x007F
0b000 (Initial value)	0x0090 to 0x00FF	0x0090 to 0x00FF
0b001	0x0080 to 0x00FF	0x0100 to 0x017F
0b010		0x0180 to 0x01FF* <sup>1</sup>
0b011		0x0200 to 0x027F
0b100		0x0280 to 0x02FF* <sup>2</sup>
0b101		0x0300 to 0x037F
0b110		0x0380 to 0x03FF
0b111		0x0400 to 0x047F

\*1: Due to the memory size limit, the available access area is up to “0x018F” in MB95F652E/F652L.

\*2: Due to the memory size limit, the available access area is up to “0x028F” in MB95F653E/F653L.